

# Small Signal Schottky Diodes

## CDBV3-00340S/C/A-G

Reverse Voltage: 40 Volts

Forward Current: 30 mA

RoHS Device



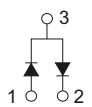
### Features

- Design for mounting on small surface.
- High speed switching application, circuit protection.
- Low turn-on voltage.

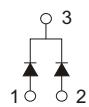
### Mechanical data

- Case: SOT-323, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Approx. weight: 0.006 grams

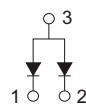
### Circuit diagram



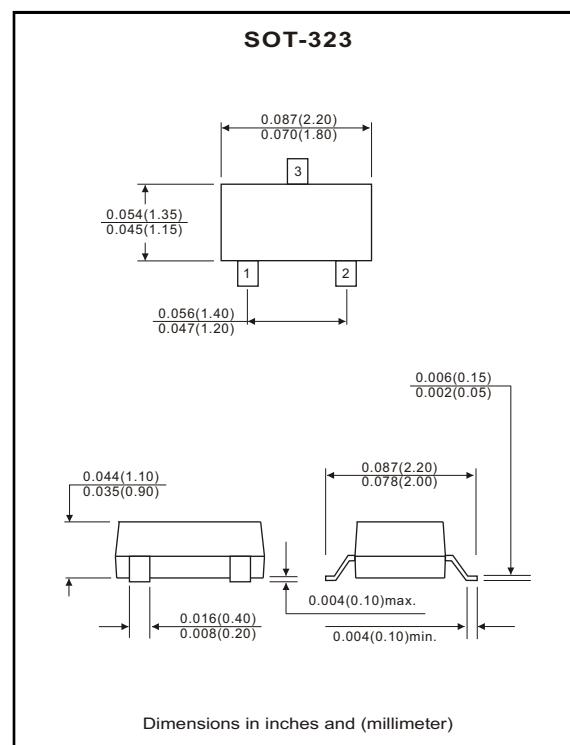
CDBV3-00340S-G



CDBV3-00340C-G



CDBV3-00340A-G



### Maximum Ratings (at Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Repetitive peak reverse voltage	V <sub>RRM</sub>				40	V
Reverse voltage	V <sub>R</sub>				40	V
Average forward current	I <sub>o</sub>				30	mA
Peak surge forward current	I <sub>FSM</sub>	8.3ms half sine-wave superimposed on rate load (JEDEC method)		200		mA
Power dissipation	P <sub>D</sub>				200	mW
Storage temperature	T <sub>TG</sub>				+125	°C
Junction Temperature	T <sub>J</sub>				+125	°C

### Electrical Characteristics (at Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =1mA			0.37	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> =10V			1	μA
Capacitance between terminals	C <sub>T</sub>	f=1MHz, V <sub>R</sub> =1V		2	5	pF

# Small Signal Schottky Diodes

## RATING AND CHARACTERISTIC CURVES (CDBV3-00340S/C/A-G)

Fig.1 Forward Characteristics

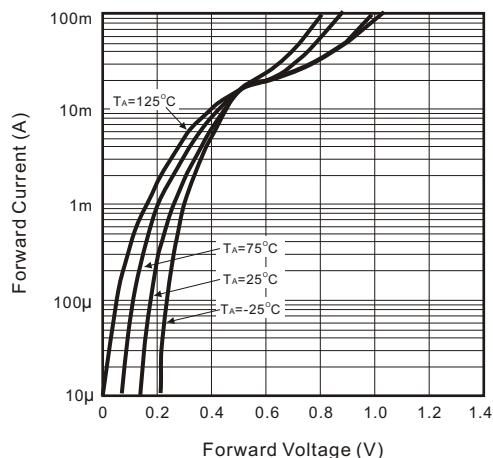


Fig.2 Reverse Characteristics

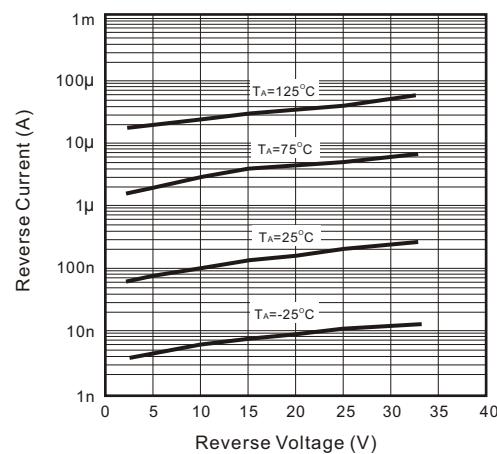


Fig.3 Capacitance Between Terminals Characteristics

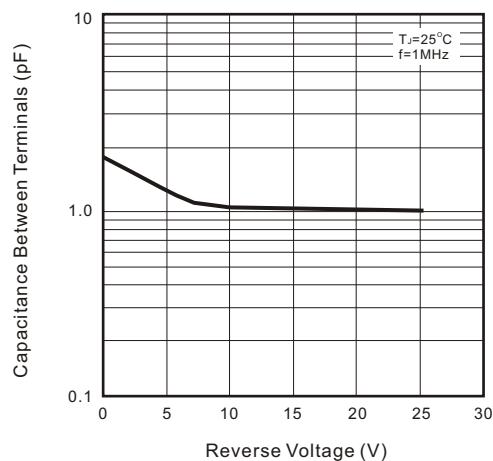


Fig.4 Power Derating Curve

